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30W TYPE-C PD3.0 / QC3.0 Power Adapter Solution with WT6632F

ON's Device	Application	Input Voltage	Output Power	Topology	I/O Isolation
NCP1342AMDAAD1 NCP4306AADZZZA NTMFS6B03 ATP104	Smart phone, PAD and NB adapter supporting PD3.0 and QC3.0	90 Vac to 264 Vac	30 W	Flyback	Isolated (3 kV)

	PD Output Specification	QC Output Specification
Output Voltage	5 V, 9 V, 12 V, 15 V, 20 V	5 V, 9 V, 12 V
Nominal Current	5V/3A, 9V/3A, 12V/2.5A, 15V/2A, 20V/1.5A	5 V / 3 A, 9 V / 2.67 A, 12 V / 2 A
Max Current	5V/3A, 9V/3A, 12V/2.5A, 15V/2A, 20V/1.5A	5 V / 3 A, 9 V / 2.67 A, 12 V / 2 A
Min Current	zero	zero

Avg. Efficiency	>90% @ 20 V 1.5 A at board end, 115 & 230 Vac
Ripple	<120mV
Standby Power	<30mW @ 5 V & 230 Vac (No cable plug in)
Power Density	1W/cm ³
Protection	Adaptive UVP, OVP, OVP, SCP, OTP
Size	57mmx36mmx15mm

Circuit Description

This design note describes a 30 W, Type C interface PD3.0, universal AC input, constant voltage power supply intended for smart phone, PAD and NB adaptor supporting PD3.0 or QC3.0 protocol, where isolation from the AC mains is required, and low cost, high efficiency, and low standby power are essential.

The featured power supply is a simple QR flyback topology utilizing ON Semiconductor's NCP1342 HF PWM controller, NCP4306D synchronous rectified controller, NTMFS6B03 synchronous MOSFET and ATP104 Switch MOSFET. This Design Note provides the complete circuit schematic details, PCB and BOM for 45 W Type C Interface PD3.0 Power adapter solution which supports PD output (5 V / 3 A, 9 V / 3 A, 12 V / 2.5 A, 15 V / 2 A, 20 V / 1.5 A).

This design combined with Weltrend WT6632F PD3.0 protocol controller to provide PD3.0 and

QC3.0 functions. This design also proposes a dual auxiliary power supply to supply PWM controller, the PWM controller is supplied by high voltage auxiliary voltage at low output voltage and supplied by low voltage auxiliary voltage at high output voltage and also shuts down zener bias of high voltage Vcc while low voltage auxiliary voltage supplies controller.

This design also uses NCP4306 synchronous rectified controller to provide high efficiency and also has no external Vcc regulator to supply synchronous controller to ensure controller can works below 3.6 V.

Key Features

- Universal AC input range (90 – 264 Vac)
- Very low standby (5 V & 230 Vac) power consumption with no cable plug in
- Very low ripple and noise
- Inherent SCP and OCP protection
- High operation frequency up to 150kHz
- High power density (1W/cm³)
- Quick switching off FET while unplugging cable and switching on FET at Vbus dropping to 5 V while plugging cable again
- Quasi-Resonant current mode control with Valley Switching
- Valley lockout avoids audible noise at valley jumping operation
- Support TYPE-C PD3.0 & QC3.0 protocol
- Adaptive Output OVP and UVP
- Open loop protection
- Board size: 57mmx36mmx19mm

Block Diagram and BOARD Photos

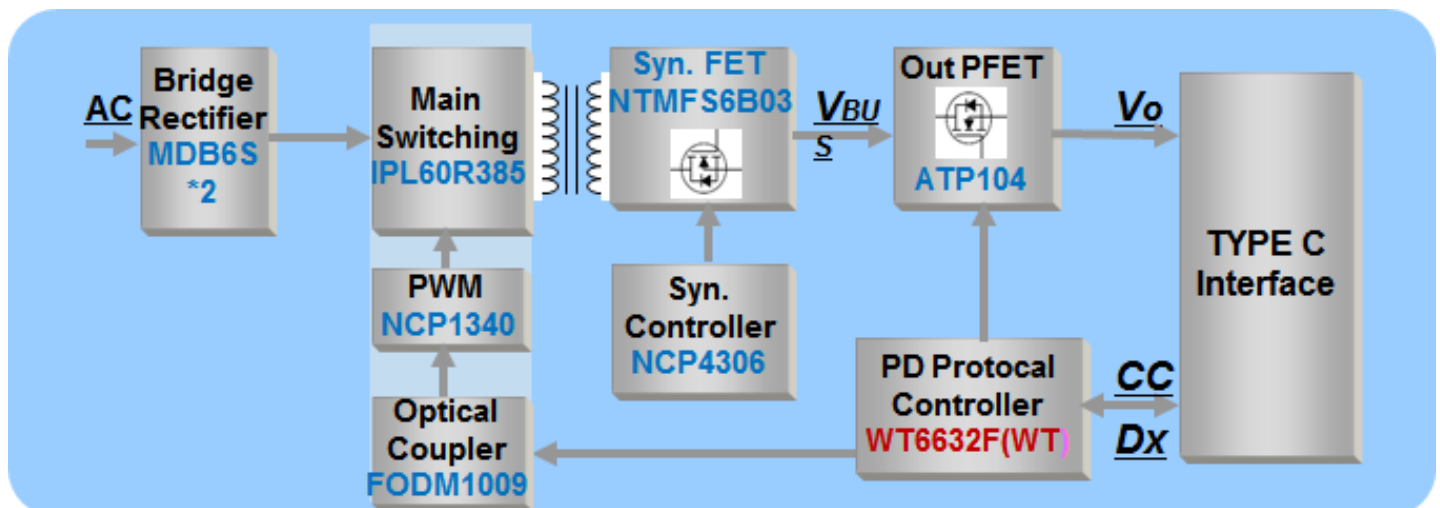


Figure 1, Overall cycle of 30W TYPE-C PD Adapter Solution



Figure 2, Side view 1 of demoboard

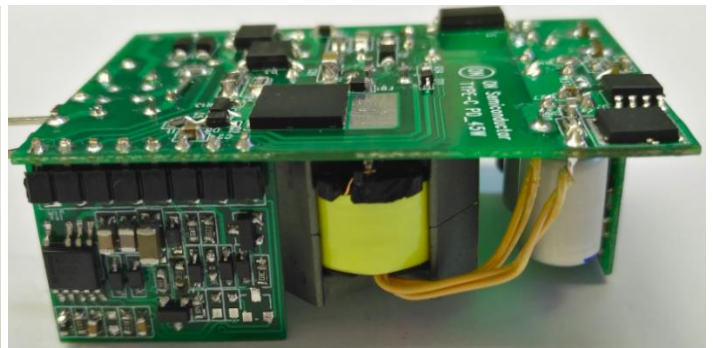
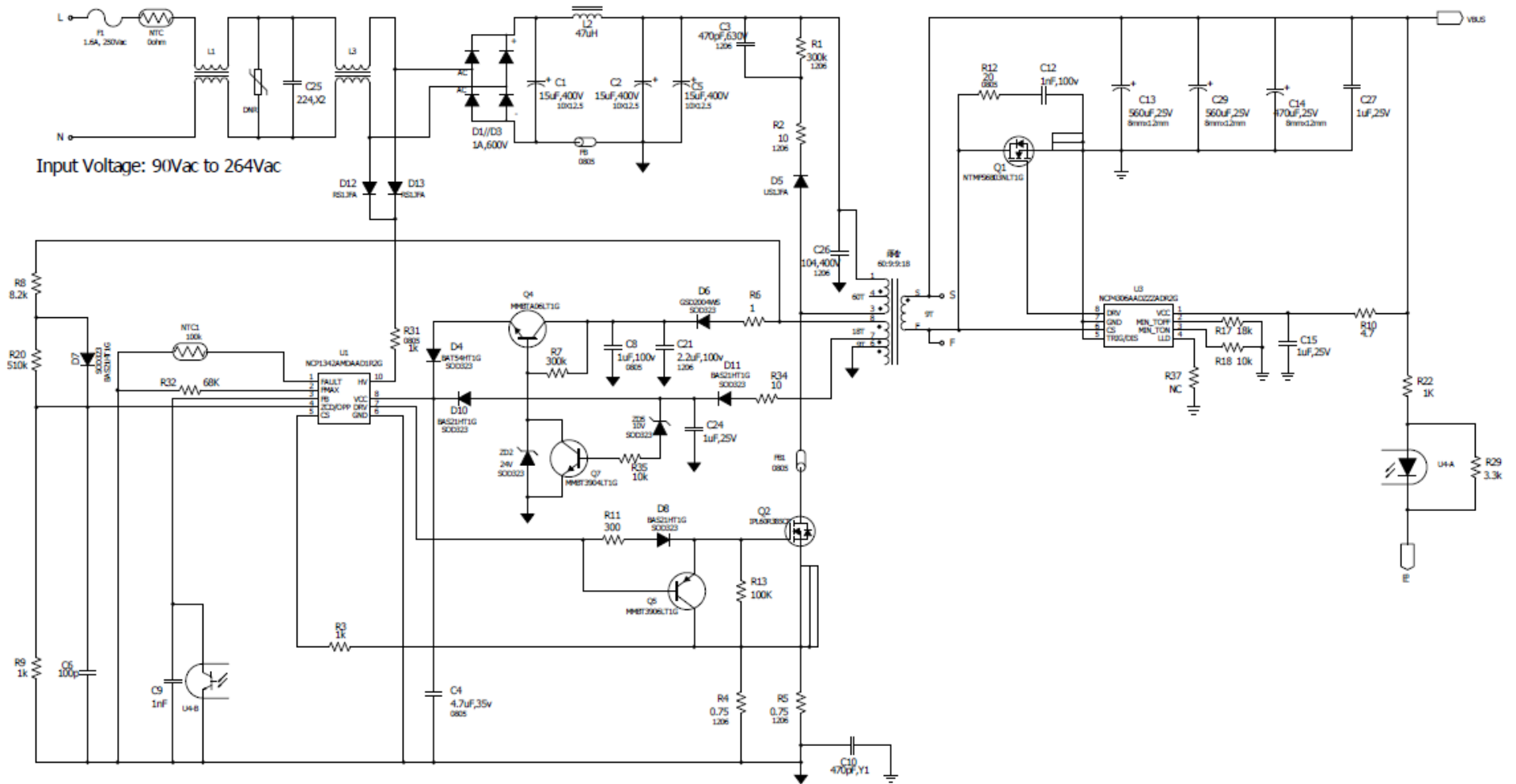
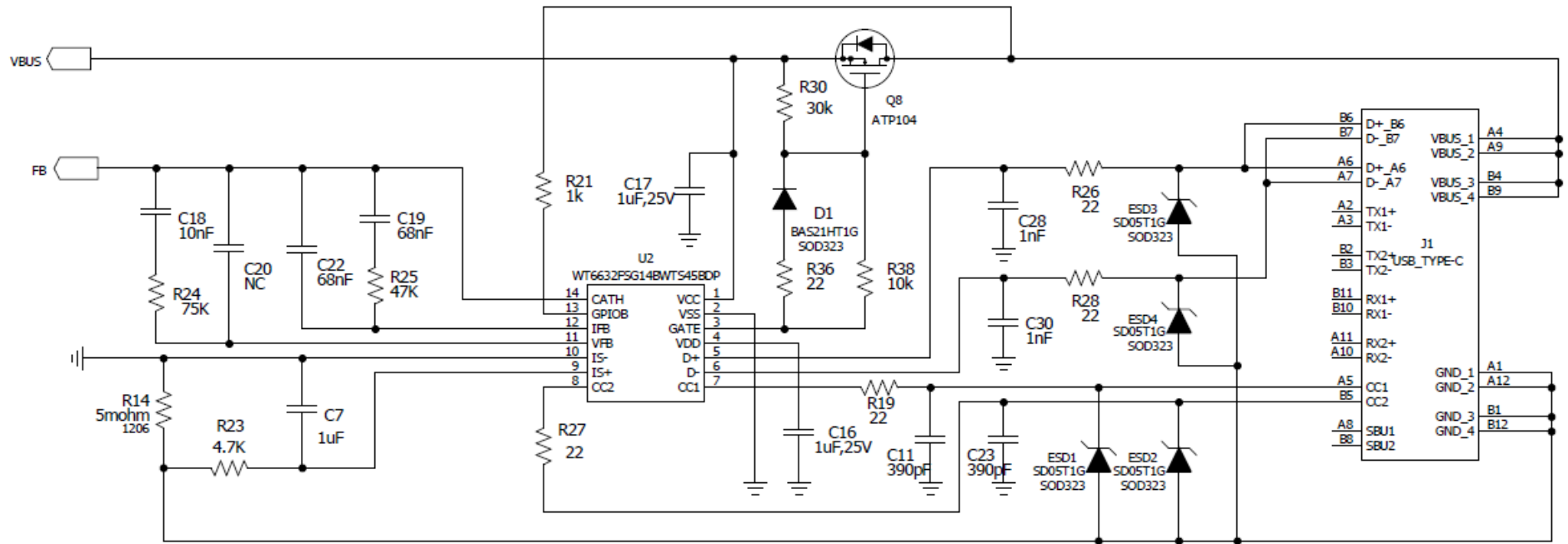


Figure 3, Side view 2 of demoboard

DN05105/D Circuit Schematic



DN05105/D Circuit Schematic (Continued)



DN05105/D
PCB

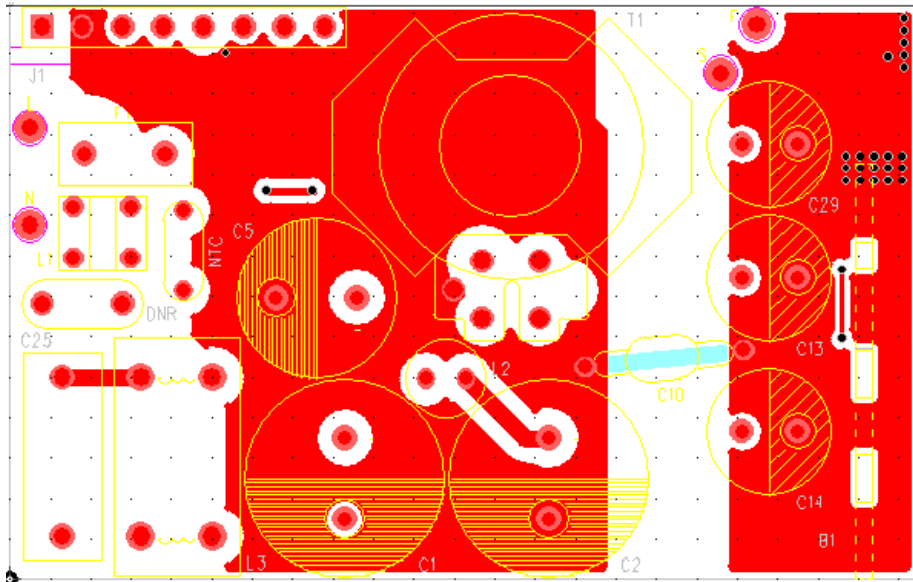


Figure 3, Top View of Mainboard's PCB

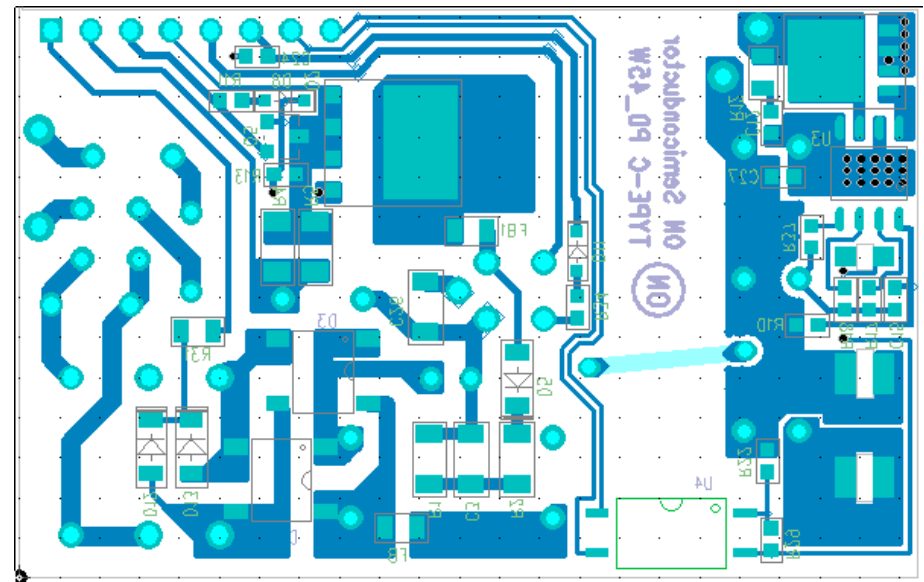


Figure 4, Bottom View of Mainboard's PCB

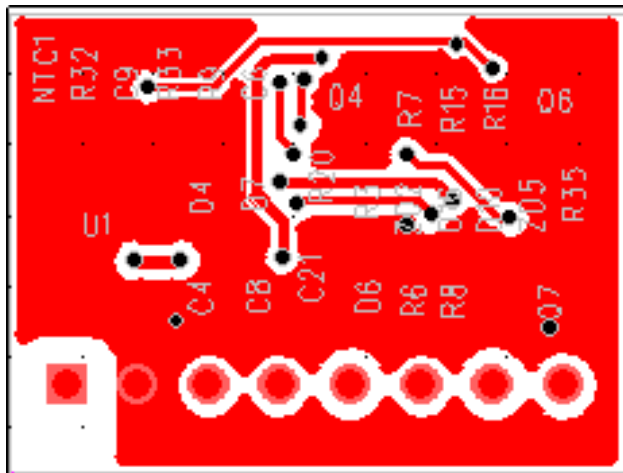


Figure 5, Top View of PWM control board's PCB

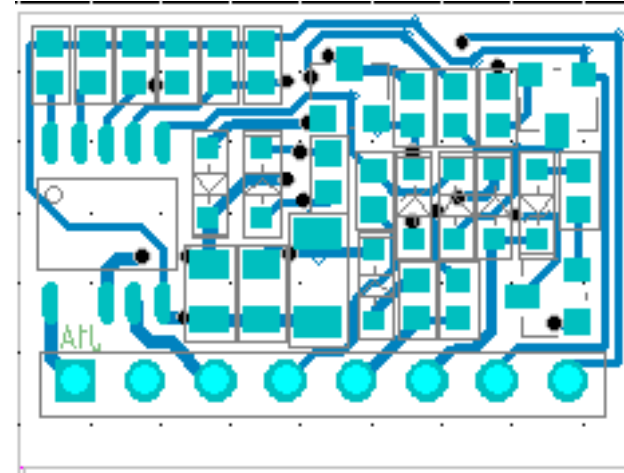


Figure 6, Bottom View of PWM control board's PCB

DN05105/D PCB Layout(Cont'd)

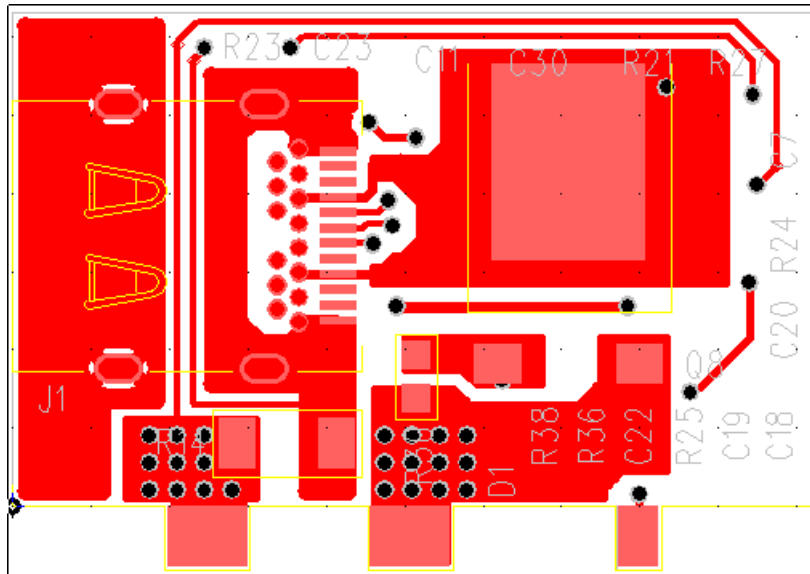


Figure 7, Top View of PD control board (WT6632F)'s PCB

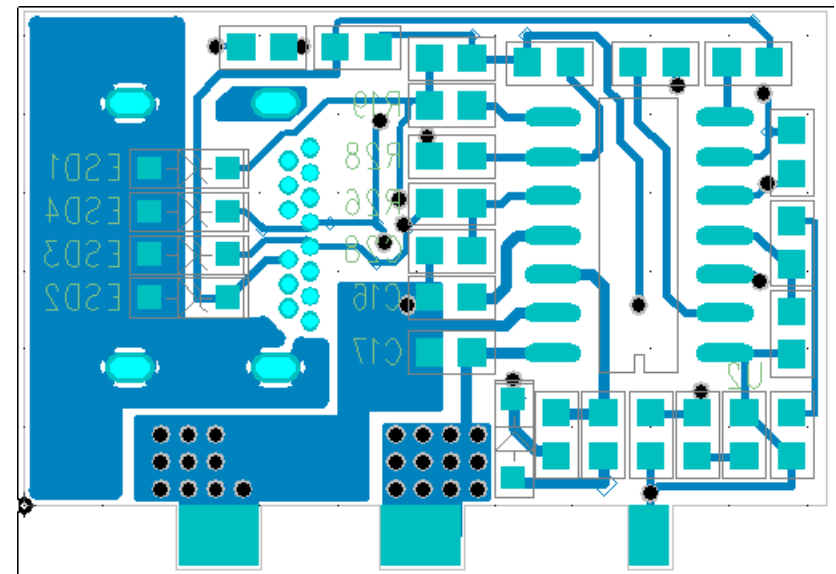


Figure 8, Bottom View of PD control board (WT6632F)'s PCB

T1 Transformer Designs (Available from Wurth Electronics)

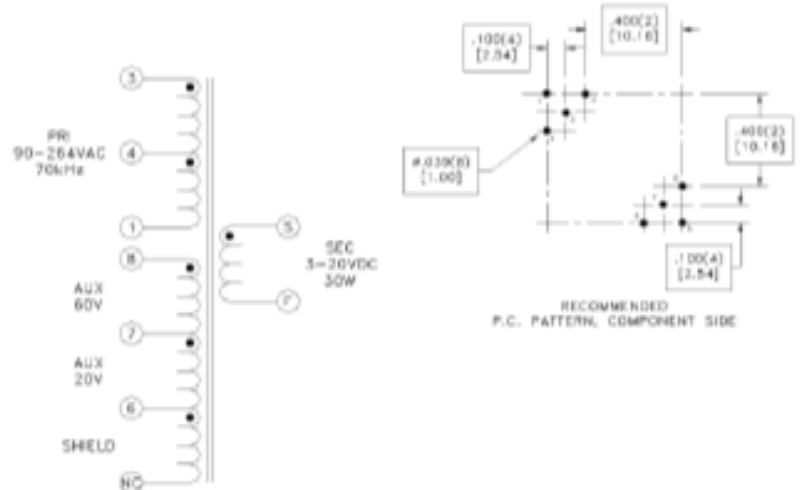
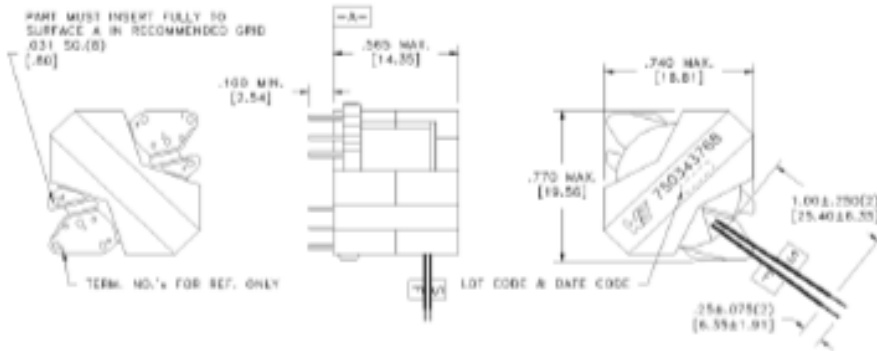
CUSTOMER TERMINAL	RoHS	LEAD(Pb)-FREE
Sn 98%, Ag 4%	Yes	Yes

more than you expect



ELECTRICAL SPECIFICATIONS @ 25°C unless otherwise noted:

PARAMETER	TEST CONDITIONS	VALUE
D.C. RESISTANCE	1-3 @20°C	0.59 ohms max.
D.C. RESISTANCE	8-F @20°C	0.03 ohms max.
D.C. RESISTANCE	6-7 @20°C	0.36 ohms max.
D.C. RESISTANCE	7-8 @20°C	0.74 ohms max.
INDUCTANCE	1-3 10kHz, 1.0V, Ls	530.00µH ±10%
LEAKAGE INDUCTANCE	1-3 tie(6+7+8+S+F), 100kHz, 100mV, Ls	12µH max.
DIELECTRIC	tie(4+5), 3000VAC, 1 second	
URNS RATIO	(3-1):(8-F)	6.67:1, ±2%
URNS RATIO	(3-1):(8-7)	3.33:1, ±2%
URNS RATIO	(3-1):(7-6)	6.67:1, ±2%



GENERAL SPECIFICATIONS:

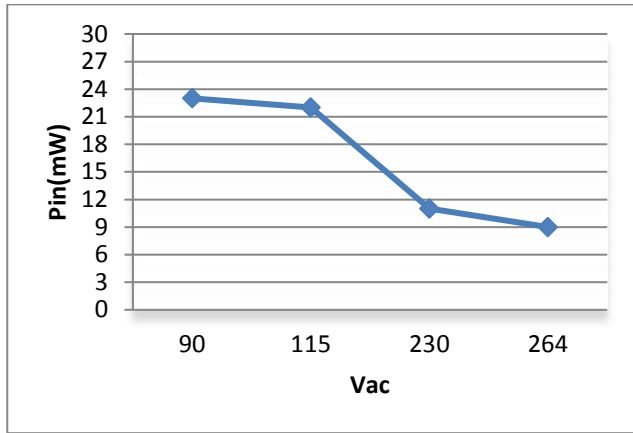
OPERATING TEMPERATURE RANGE: -40°C to +125°C including temp rise.
 Designed to comply with the following requirements as defined by IEC60950-1, EN60950-1, UL60950-1/CSA60950-1 and AS/NZS60950.1:
 - Reinforced insulation for a primary circuit at a working voltage of 285Vrms, 400Vpeak, Overvoltage Category II.

Wire Insulation & RoHS status not affected by wire color. Wire Insulation color may vary depending on availability.

DFM	Packaging Specifications	<p>CONVENTION PLACEMENT</p>	Tolerances unless otherwise specified: Angles: ±1° Decimals: ±.005 [.13] Fractions: ±1/64 Footprint: ±.001 [.03]	DRAWING TITLE	PART NO.
DATE	Method: Tray		This drawing is dual dimensioned. Dimensions in brackets are in millimeters.	TRANSFORMER	750343768
ENG	PKG-0103				
REV.	00				
DATE	11/10/2017				SPECIFICATION SHEET 1 OF 1

Standby Power at 5V Output (Cable unplug) @ 90 Vac to 264 Vac Input

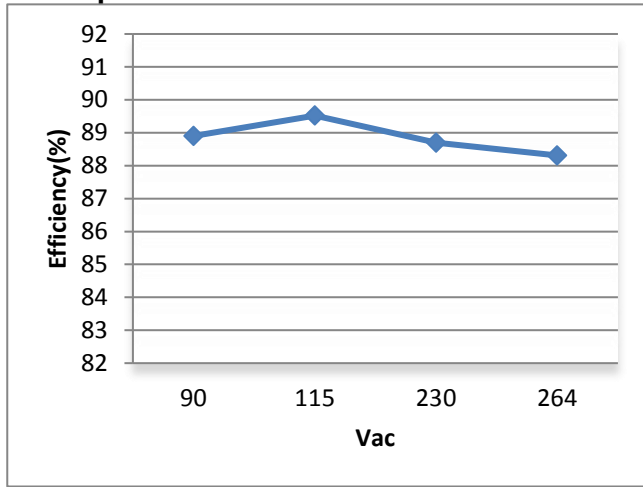
Test condition: all efficiency are tested at board end



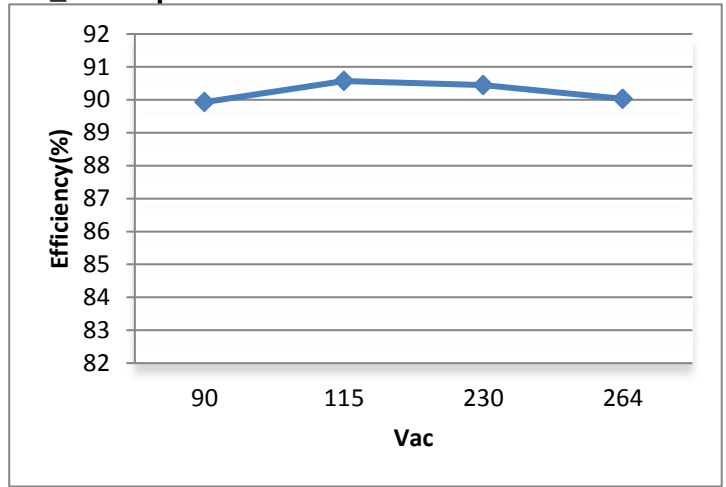
Average Efficiency

Test condition: all efficiency are tested at board end

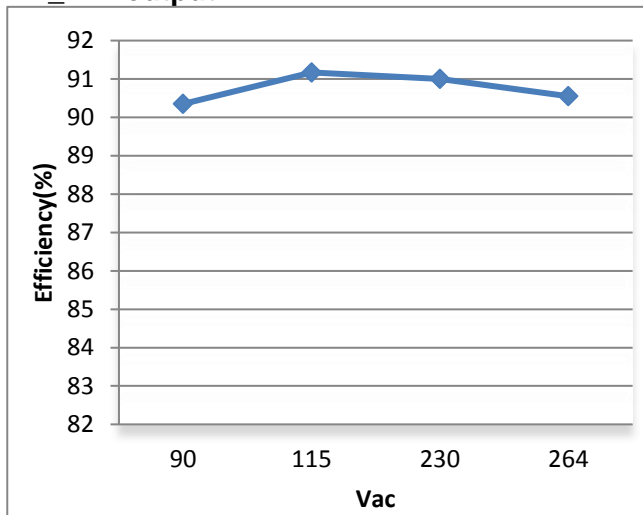
5V output



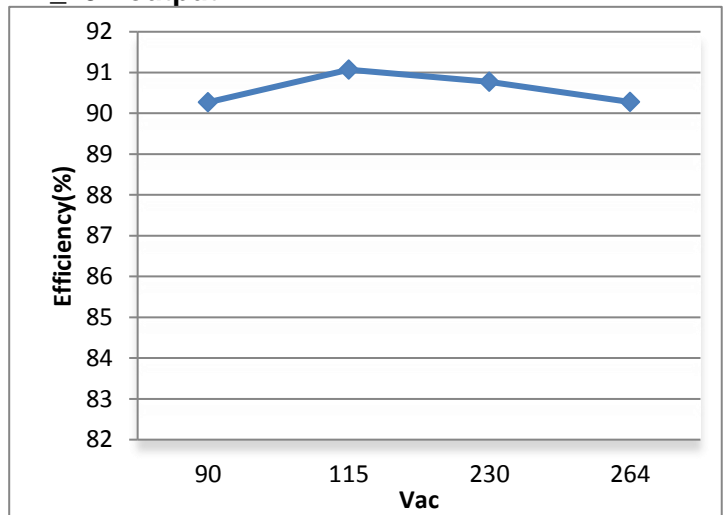
PD_9V output



PD_12V output



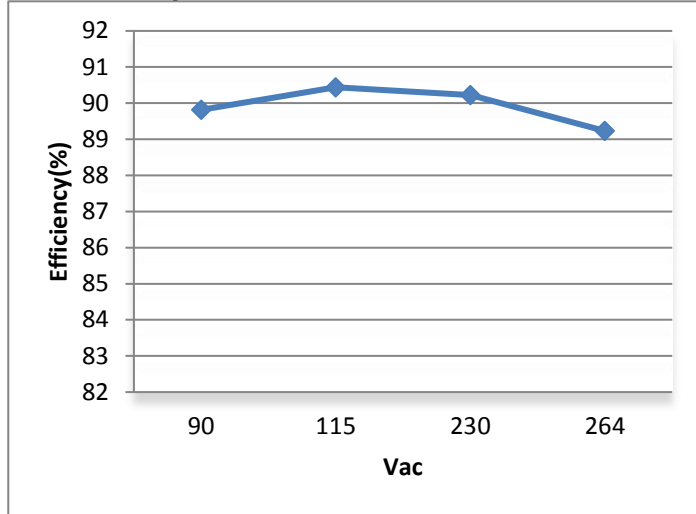
PD_15V output



Average Efficiency (Continued)

Test condition: all efficiency are tested at board end

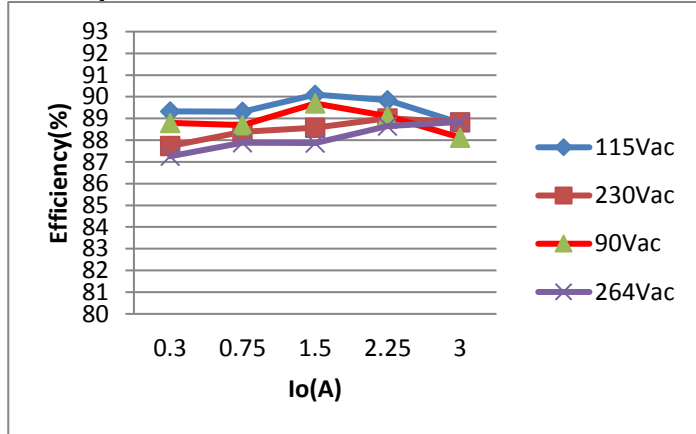
PD_20V output



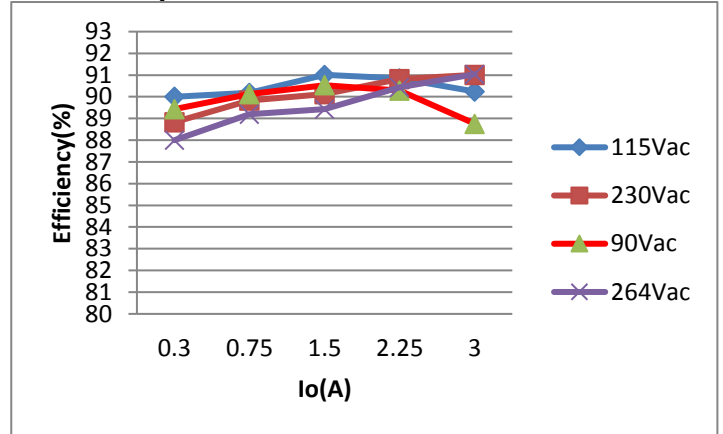
Efficiency vs Output Load Curves

Test condition: all efficiency are tested at board end

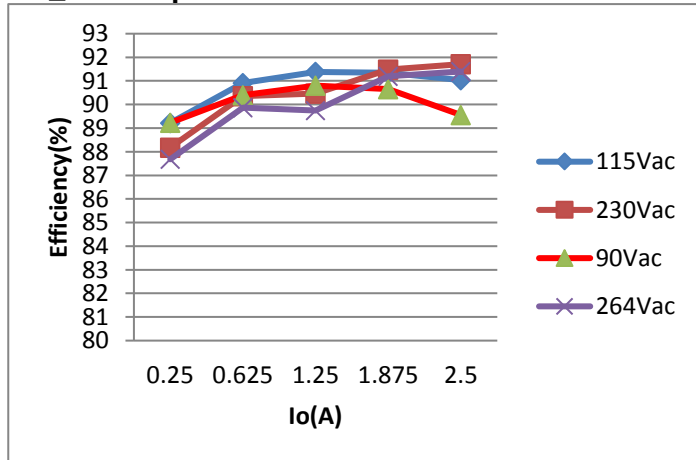
5V output



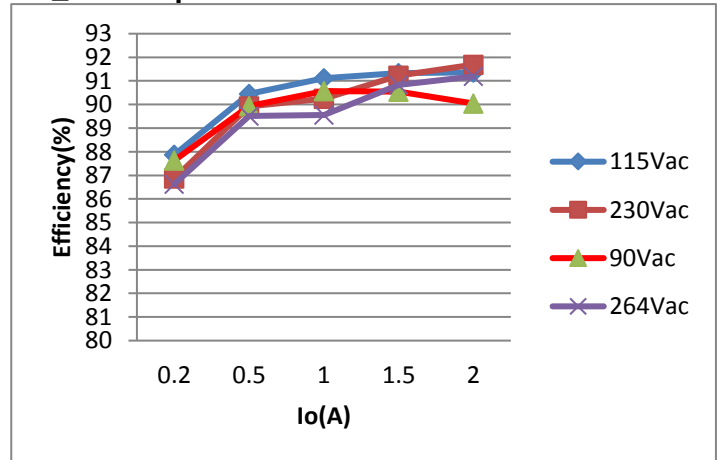
PD_9V output



PD_12V output



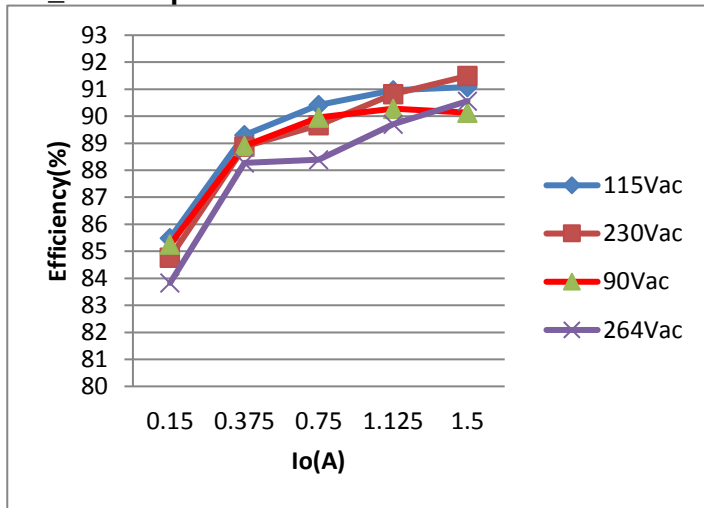
PD_15V output



Efficiency vs Output Load Curves(Continued)

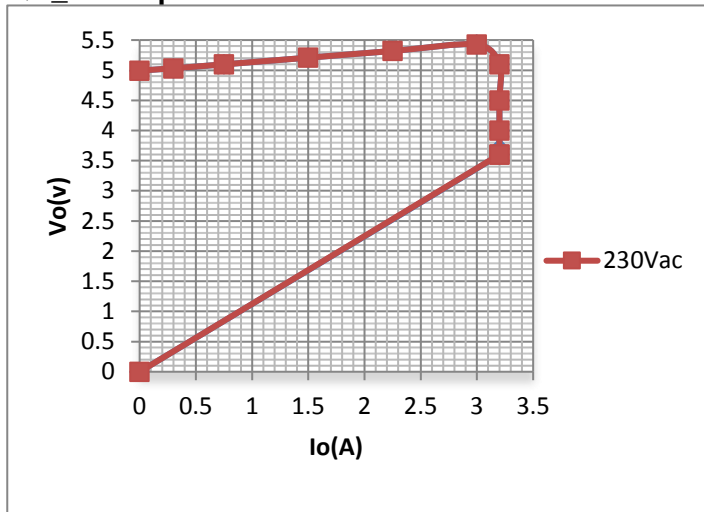
Test condition: all efficiency are tested at board end

PD_20V output

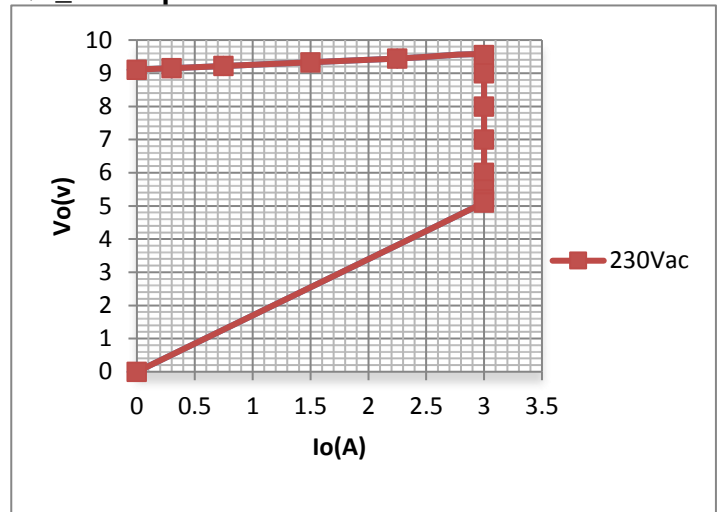


I-V Curves

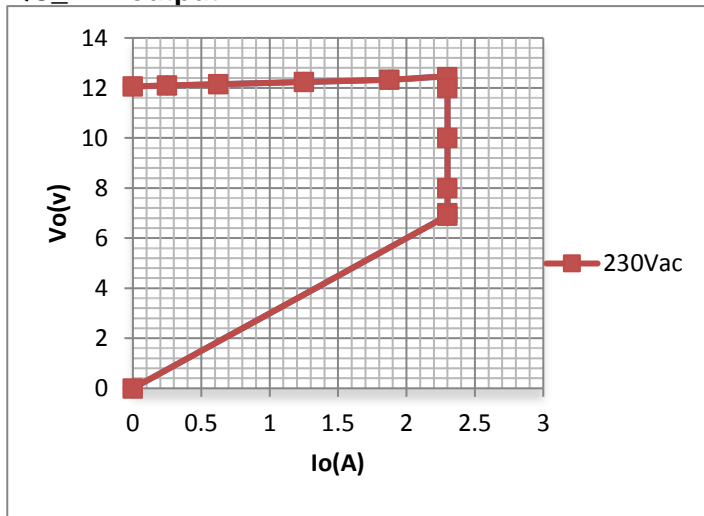
QC_5V output



QC_9V output

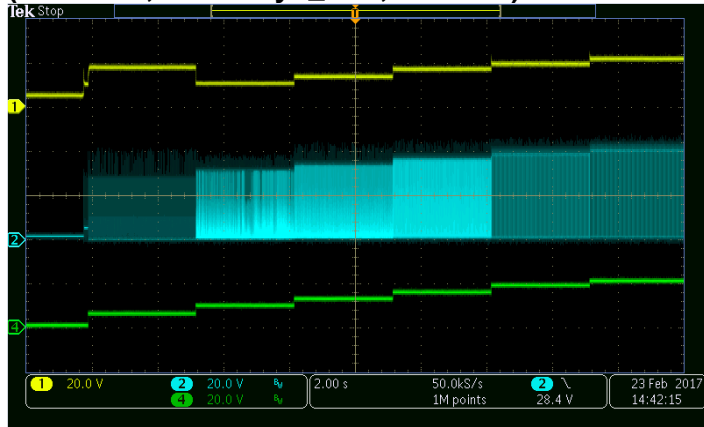


QC_12V output



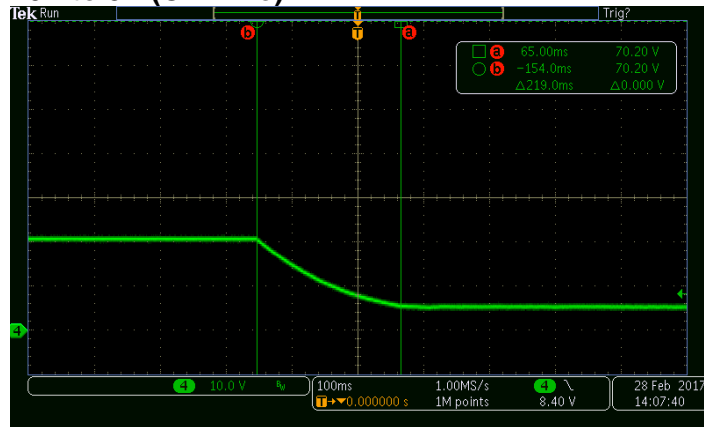
Power On and PD Volatge Change

(CH1: Vcc, CH2: Vsyn_FET, CH4: Vo)



PD Transition with PD Emulator

20V to 5V (CH4: Vo)



Discharge Time @ Unplug cable

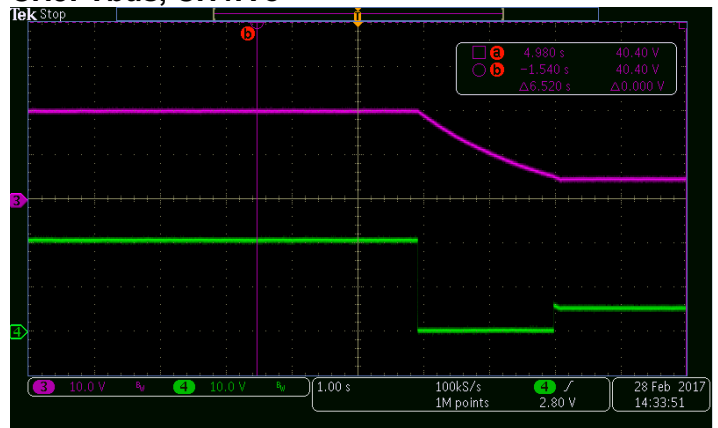
PD (20V to 5V)

(CH1: Vcc, CH2: Vsyn_FET, CH3: Vbus, CH4: Vo)



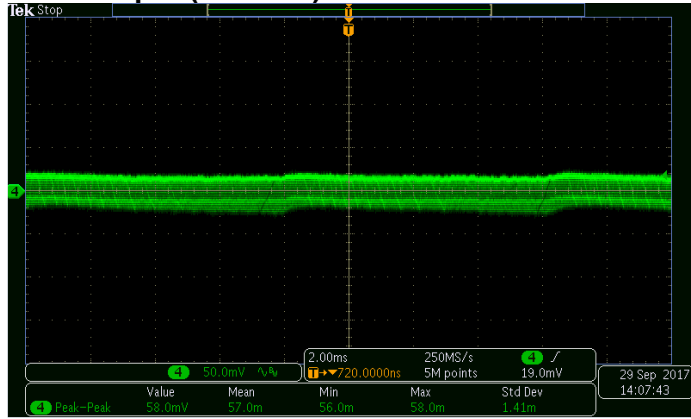
Quick Unplug/Plug Cable

CH3: Vbus, CH4:Vo

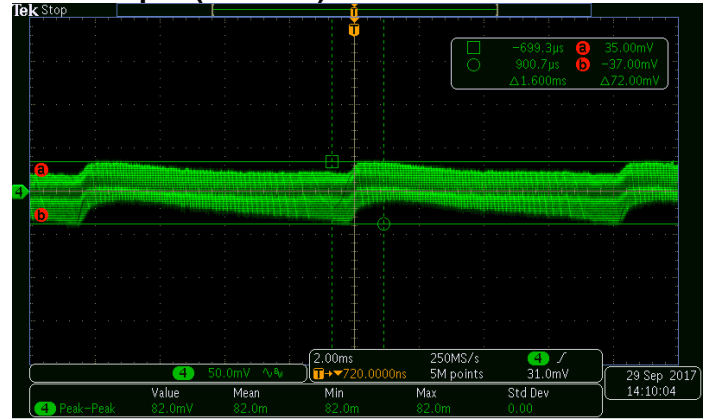


Output Ripple @ 90 Vac Input, full load

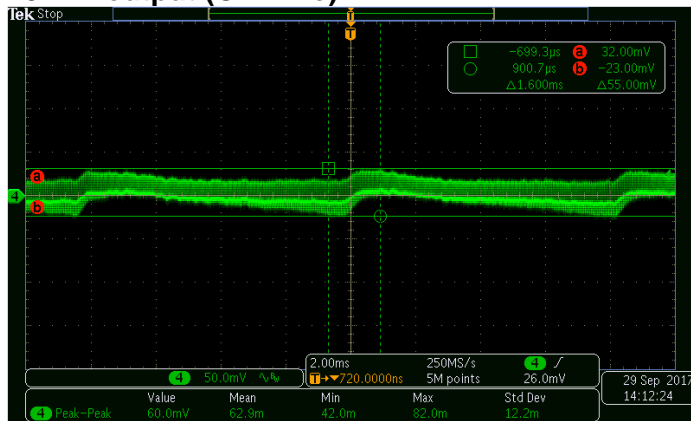
5V3A output (CH4: Vo)



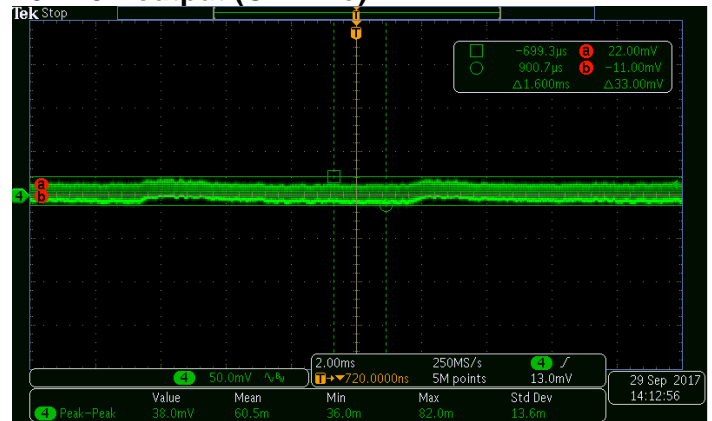
9V3A output (CH4: Vo)



15V2A output (CH4: Vo)

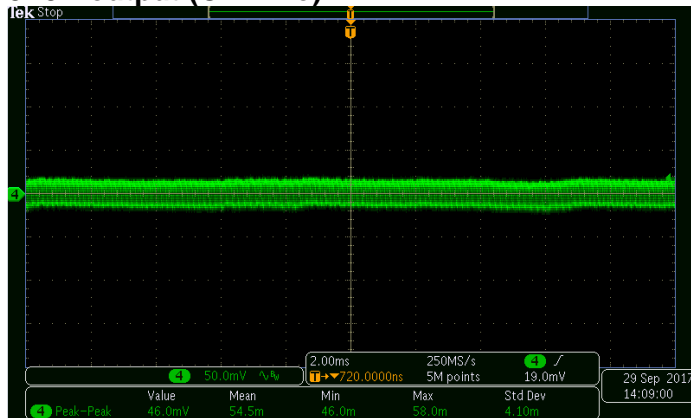


20V1.5A output (CH4: Vo)

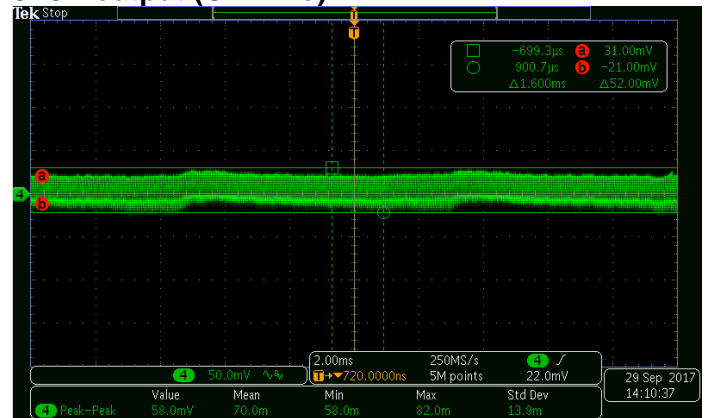


Output Ripple @ 115 Vac Input, full load

5V3A output (CH4: Vo)

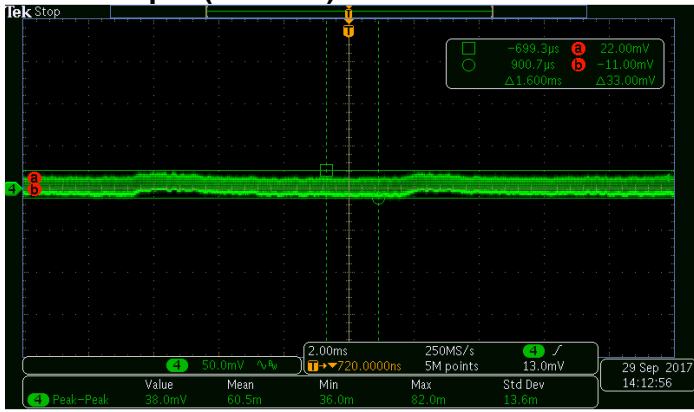


9V3A output (CH4: Vo)

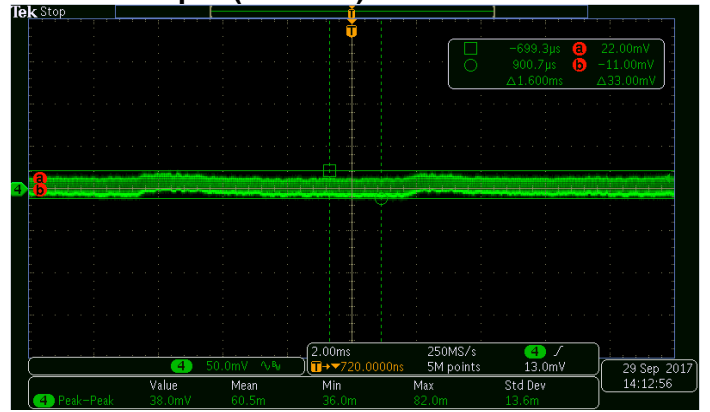


DN05105/D

15V2A output (CH4: Vo)

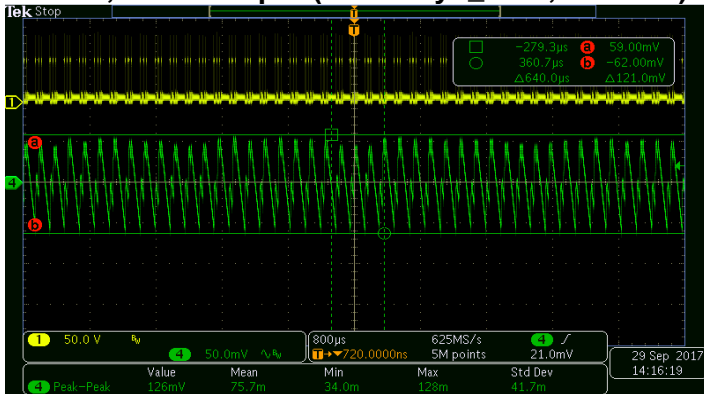


20V1.5A output (CH4: Vo)

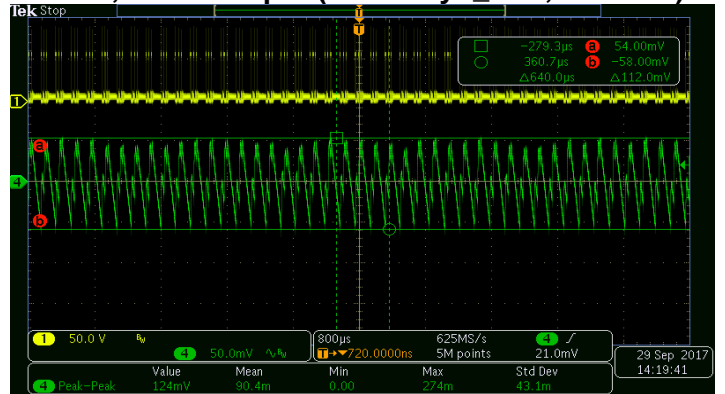


Output Ripple @ High Line & Light Load

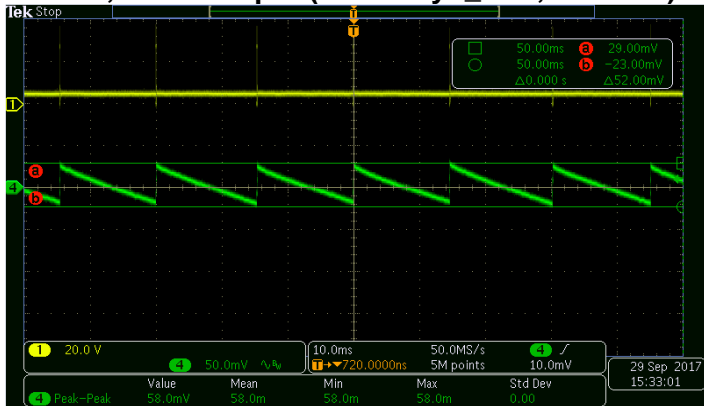
230Vac, 5V/1A output (CH1: Vsyn_FET, CH4: Vo)



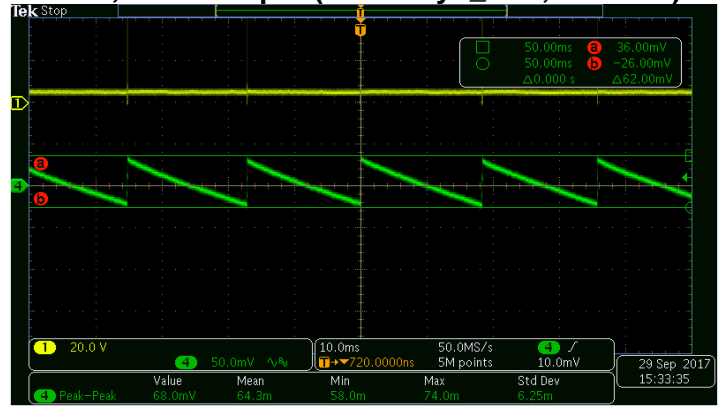
264Vac, 5V/1A output (CH1: Vsyn_FET, CH4: Vo)



115Vac, 5v/0A output (CH1: Vsyn_FET, CH4: Vo)

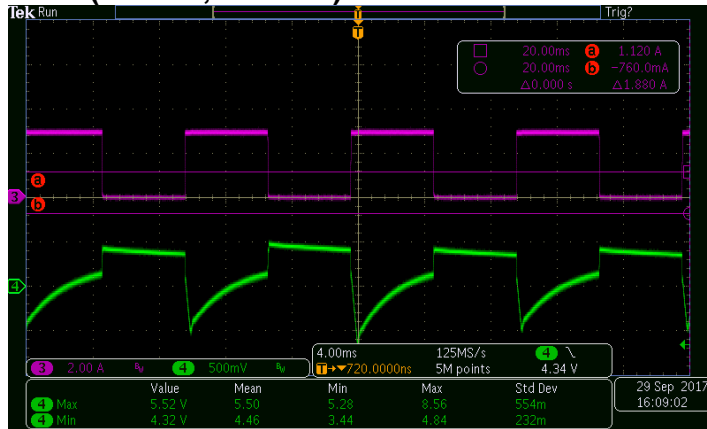


230Vac, 5v/0A output (CH1: Vsyn_FET, CH4: Vo)



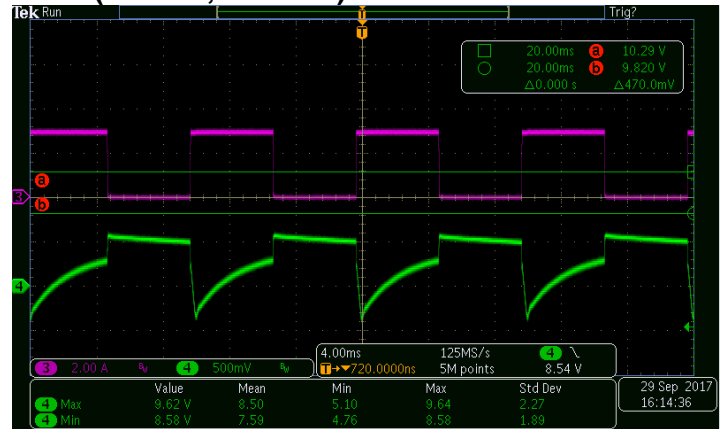
Dynamic Test @ 115 Vac Input

5V3A (CH3: Io, CH4: Vo)



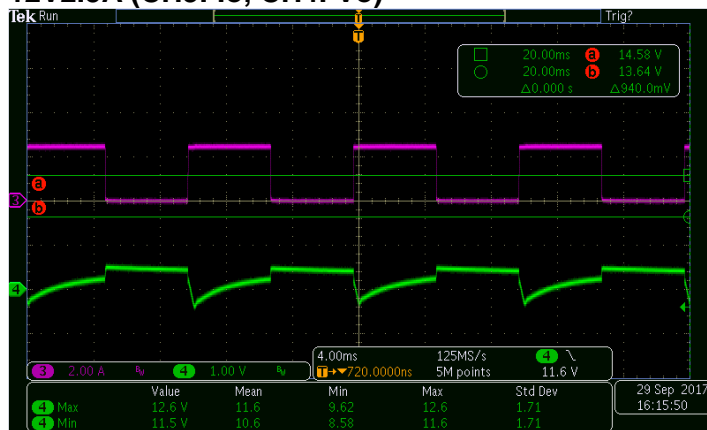
Test condition: 0-3A, 10mS cycle, 125mA/US
1m cable, tested at E-load

9V3A (CH3: Io, CH4: Vo)



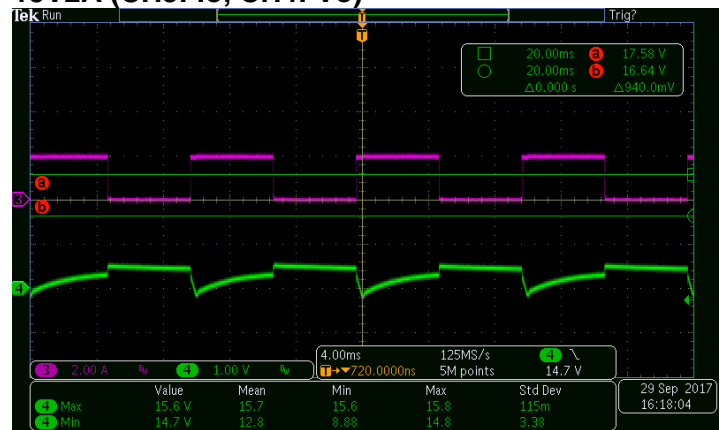
Test condition: 0-3A, 10mS cycle, 125mA/US
1m cable, tested at E-load

12V2.5A (CH3: Io, CH4: Vo)



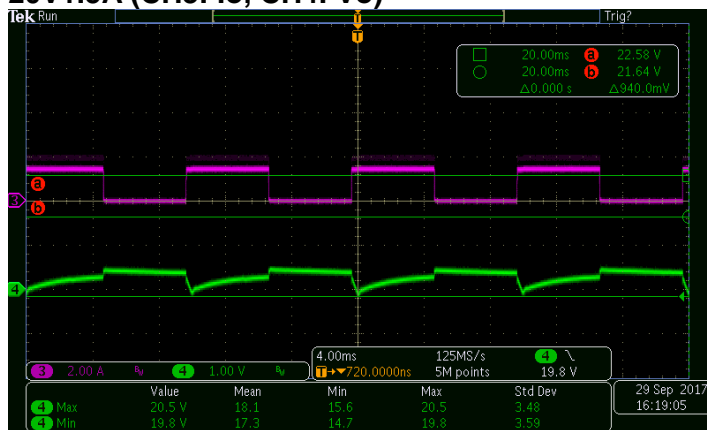
Test condition: 0-2.5A, 10mS cycle, 125mA/US
1m cable, tested at E-load

15V2A (CH3: Io, CH4: Vo)



Test condition: 0-2A, 10mS cycle, 125mA/US
1m cable, tested at E-load

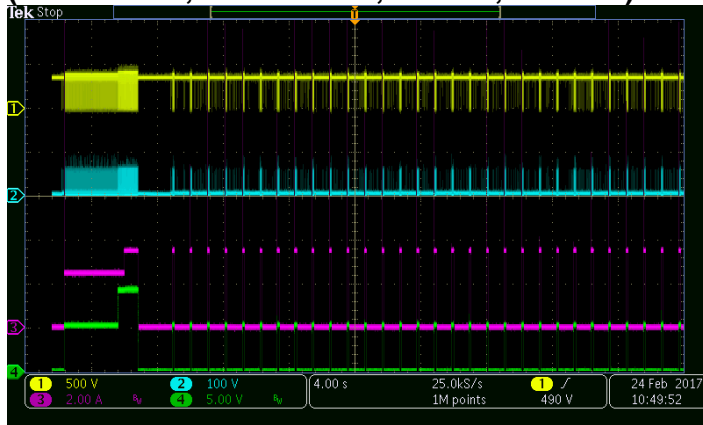
20V1.5A (CH3: Io, CH4: Vo)



Test condition: 0-1.5A, 10mS cycle, 125mA/US
1m cable, tested at E-load

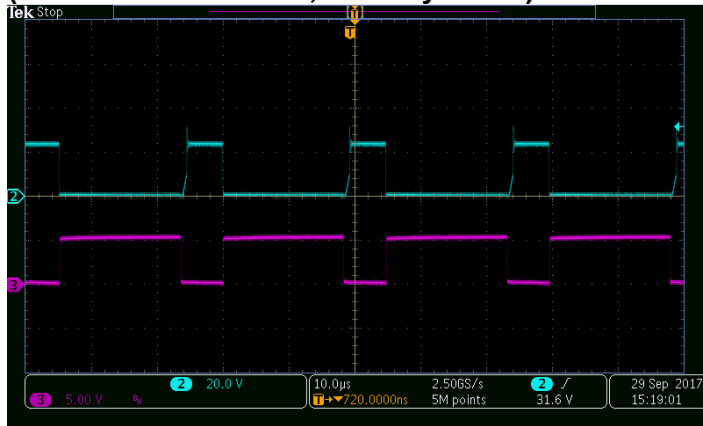
OCV @ 264 Vac Input, 9 Vdc Output

(CH1: Vdrain, CH2: Vtr sec, CH3: Io, CH4: Vo)

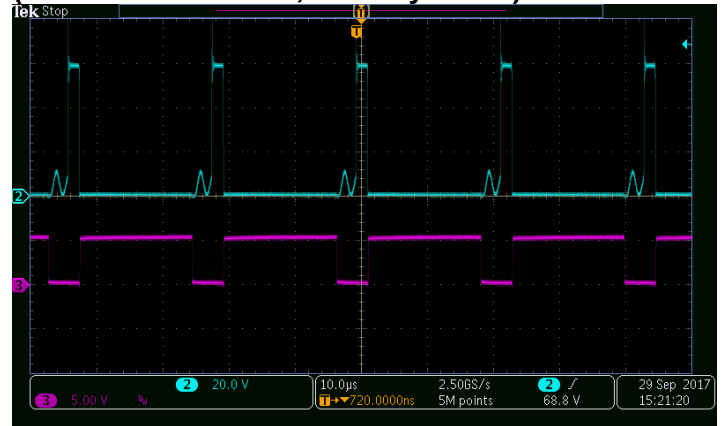


Synchronic Drive

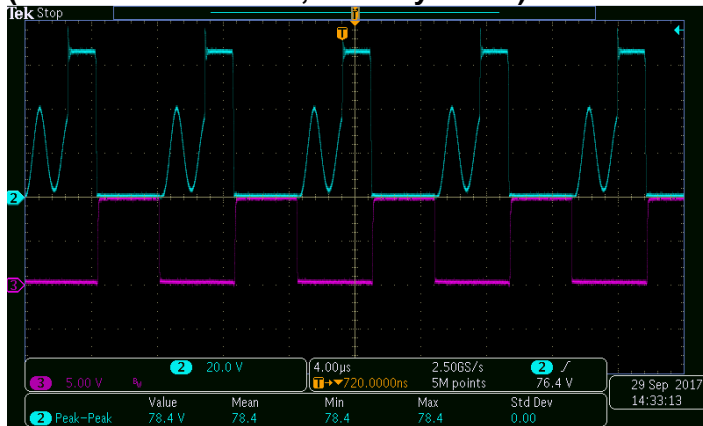
90 Vac input, 5V3A output
(CH2: Sec. FET Drain, CH3: Syn DRV)



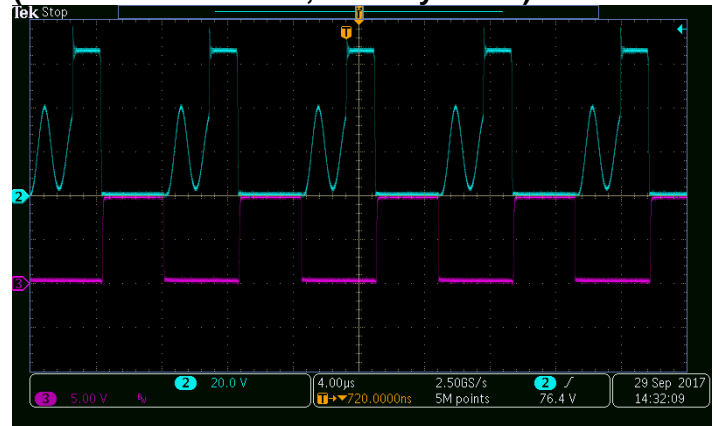
264 Vac input, 5V3A output
(CH2 Sec. FET Drain, CH3: Syn DRV)



230 Vac input, 15V2A output
(CH2: Sec. FET Drain, CH3: Syn DRV)

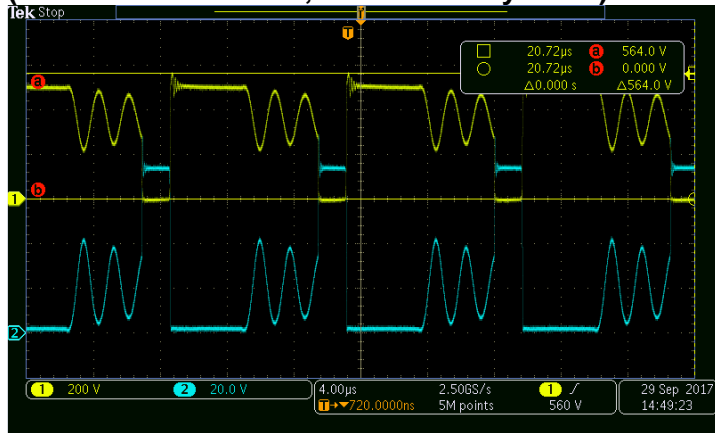


230 Vac input, 20V1.5A output
(CH2: Sec. FET Drain, CH3: Syn DRV)



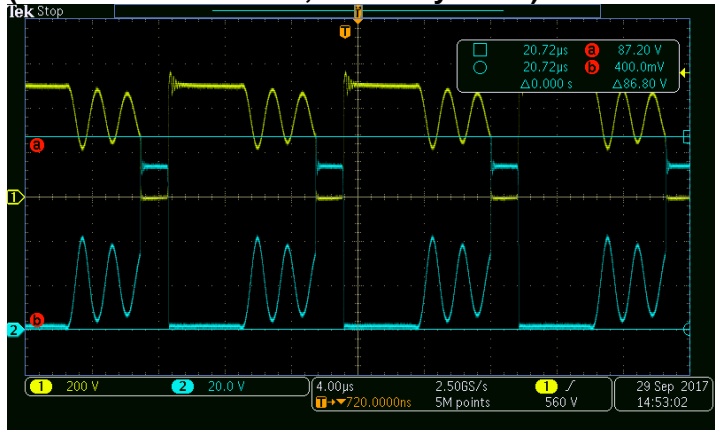
Primary FET Drain Voltage @ 264 V_{ax} input, 20V1.5A output

(CH1: Pri. FET V_{drain}, CH2: Sec. V_{syn} FET)



Synchronic FET Drain Voltage @ 264 V_{ax} input, 20V1.5A output

(CH1: Pri. FET V_{drain}, CH2: V_{syn} FET)



Thermal Image @ 20V2.25A Output

Input	Component Side	Back side
90 Vac	<p>FLUKE 76.5°C 自动 2 83.3 最大 80.8 最小 25.8 24.8 ε=0.95 BG=22.0 T=100% 9/29/17 05:01:59 PM</p>	<p>FLUKE 72.9°C 自动 2 87.8 最大 86.4 最小 27.9 27.4 ε=0.95 BG=22.0 T=100% 9/29/17 05:02:20 PM</p>
115 Vac	<p>FLUKE 75.7°C 自动 2 81.7 最大 81.4 最小 24.2 23.4 ε=0.95 BG=22.0 T=100% 9/29/17 05:09:58 PM</p>	<p>FLUKE 72.6°C 自动 1 79.8 最大 80.0 最小 28.6 27.5 ε=0.95 BG=22.0 T=100% 9/29/17 05:09:21 PM</p>
230 Vac	<p>FLUKE 75.9°C 自动 1 81.7 最大 80.8 最小 25.4 25.2 ε=0.95 BG=22.0 T=100% 9/29/17 05:24:11 PM</p>	<p>FLUKE 68.2°C 自动 1 78.7 最大 77.8 最小 27.0 26.0 ε=0.95 BG=22.0 T=100% 9/29/17 05:24:31 PM</p>
264 Vac	<p>FLUKE 81.9°C 自动 2 92.3 最大 91.0 最小 25.5 23.9 ε=0.95 BG=22.0 T=100% 9/29/17 05:32:58 PM</p>	<p>FLUKE 78.6°C 自动 1 118 最大 91.8 最小 26.2 25.8 ε=0.95 BG=22.0 T=100% 9/29/17 05:32:39 PM</p>

**DN05105/D
BOM**

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
1	1	C6	Ceramic Capacitor	/885012206077	WE	100p	603	Capacitor, Ceramic, 50V, 10%
2	1	C26	Ceramic Capcitor	C3216X7T2W104K	TDK	104, 400V	1206	Capacitor, Ceramic, SMD, 5%
3	1	C18	Ceramic Capacitor	/885012006051	WE	10nF	603	Capacitor, Ceramic, 50V, 10%
4	3	C9 C28 C30	Ceramic Capacitor	/885012206083	WE	1nF	603	Capacitor, Ceramic, 50V, 10%
5	1	C12	Ceramic Capacitor	/885012207116	WE	1nF, 100v	603	Capacitor, Ceramic, SMD, 5%
6	1	C8	Ceramic Capacitor	C2012X7S2A105K	TDK	1uF, 100v	805	Capacitor, Ceramic, 100V, 10%
7	6	C7 C15-17 C24	Ceramic Capacitor	/885012206076	WE	1uF, 25V	603	Capacitor, Ceramic, 25V, 10%
8	1	C21	Ceramic Capacitor	C3216X7S2A225K	TDK	2.2uF, 100v	1206	Capacitor, Ceramic, 100V, 10%
9	1	C25	X2 Capcitor	/890324023028	WE	224, X2	THT, 10m	X2 capacitor, Safety standard approved, 10%
10	2	C11 C23	Ceramic Capacitor	std	std	390pF	603	Capacitor, Ceramic, 50V, 10%
11	1	C4	Ceramic Capacitor	C2012X7R1V475K	TDK	4.7uF, 35v	805	Capacitor, Ceramic, 35V, 10%
12	1	C3	Ceramic Capcitor	C3216C0G2J471J	TDK	470pF, 630V	1206	Capacitor, Ceramic, Chip, 5%
13	1	C10	Ceramic Capcitor	CS65-B2GA101KYNF	TDK	470pF, Y1	Lead typ	HV Ceramic Capacitor, safety standard approved
14	2	C19 C22	Ceramic Capacitor	/885012206094	WE	68nF	603	Capacitor, Ceramic, 50V, 10%
15	1	C20	Ceramic Capacitor	Std	std	NC	603	Capacitor, Ceramic, 50V, 10%
16	1	D1//D3	Bridge rectifier	MDB6S	FSC	1A, 600V	micro-DIP	Bridge Rectifier, 600V, 1A
17	1	DNR	Varistor	820573011	WE	10D471K	TH	Varistor, 10D471K
18	5	D1 D7 D8 D10	Switching diode	BAS21HT1G	ON	0.2A, 250V	SOD323	Switching diode, SMD
19	1	D6	Switching diode	GSD2004WS	Vishay	0.2A, 300V	SOD323	Switching diode, SMD
20	1	D4	Switching diode	BAT54HT1G	ON	0.2A, 30V	SOD323	Switching diode, SMD
21	1	D5	Ultrafast rectifier	US1JFA	ON(FSC)	0.8A, 600V	SOD123FL	Standard Rectifier, 0.8A, 600V
22	2	D12-13	Standard rectifier	RS1JFA	ON(FSC)	0.8A, 600V	SOD123FL	Standard Rectifier, 0.8A, 600V
23	1	FB	Ferrite bead	UPZ2012E102-1R5	Sunlord/WE		805	1000ohm@100MHz
24	1	FB1	Ferrite bead	UPZ2012E601-2R0	Sunlord/WE		805	600ohm@100MHz
25	1	L3	Common filter	/744821110	WE	10mH	TH type	CM Filter, T type core
26	1	L1	Common filter	150-1327	WE	500uH	TH	T type, 6.3x3x3, 11T, 0.2mmx2 in parallel
27	1	F1	Fuse	20T-016H	Hollyfu	1.6A, 250V	axial lead	Micro Fuse, 1.6A/250V
28	1	Q4	NPN Transistor	MMBTA06LT1G	ON		SOT23	General NPN Transistor, SMD
29	1	Q7	NPN Transistor	MMBT3904LT1G	ON		SOT23	General NPN Transistor, SMD
30	1	Q5	PNP Transistor	MMBT3906LT1G	ON		SOT23	General PNP Transistor, SMD
31	1	U3	Syn. rectified controller	NCP4306AADZZZAD1	ON		S08	Syn. Rectified Controller
32	1	U1	PWM Controller	NCP1342AMDAAD1R2	ON		SOP9	QR PWM controller
33	1	NTC	NTC	replaced by jump	Sunlord	0ohm	lead type	9mm Die, 2.5ohm
34	1	NTC1	NTC	SDNT1608X104J425	Sunloar	100k	603	
35	1	U4	Optical coupler	FODM1009	ON(FSC)		LSOP4	optical coupler, standard SOP package
36	1	Q8	PMOS	ATP104	ON	-30V, 8.4mA	ATPAK	PMOS

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BOM (Continued)

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
37	1	L2	Axial leaded fixe	/7447462470	Würth	47uH	lead type	Axial leaded fixed inductor
38	1	Q2	MOSFET	IPL60R385CP	Infineon		THINKPAK-8X8	MOSFET, NChan, 600V
39	1	R6	Resistor	Std	Std	1	603	Resistor, Chip, 1/8W, 1%
40	1	R34	Resistor	Std	Std	10	603	Resistor, Chip, 1/8W, 1%
41	1	R13	Resistor	Std	Std	100K	603	Resistor, Chip, 1/8W, 1%
42	3	R18 R35 R38	Resistor	Std	Std	10k	603	Resistor, Chip, 1/8W, 1%
43	1	R17	Resistor	Std	Std	18k	603	Resistor, Chip, 1/8W, 1%
44	4	R3 R9 R21 R22	Resistor	Std	Std	1k	603	Resistor, Chip, 1/8W, 1%
45	5	R19 R26-28 R3	Resistor	Std	Std	22	603	Resistor, Chip, 1/8W, 1%
46	1	R29	Resistor	Std	Std	3.3k	603	Resistor, Chip, 1/8W, 1%,
47	1	R11	Resistor	Std	Std	300	603	Resistor, Chip, 1/8W, 1%
48	1	R7	Resistor	Std	Std	300k	603	Resistor, Chip, 1/8W, 1%
49	1	R30	Resistor	Std	Std	30k	603	Resistor, Chip, 1/8W, 1%
50	1	R10	Resistor	Std	Std	4.7	603	Resistor, Chip, 1/8W, 1%
51	1	R23	Resistor	Std	Std	4.7K	603	Resistor, Chip, 1/8W, 1%
52	1	R25	Resistor	Std	Std	47K	603	Resistor, Chip, 1/8W, 1%
53	1	R20	Resistor	Std	Std	510k	603	Resistor, Chip, 1/8W, 1%
54	1	R32	Resistor	Std	Std	68K	603	Resistor, Chip, 1/8W, 1%
55	1	R24	Resistor	Std	Std	75K	603	Resistor, Chip, 1/8W, 1%
56	1	R8	Resistor	Std	Std	8.2k	603	Resistor, Chip, 1/8W, 1%
57	1	R37	Resistor	Std	Std	NC	603	Resistor, Chip, 1/8W, 1%
58	2	R4-5	Resistor	ERJ8BQFR075V	Panason	0.75	1206	Resistor, Chip, 1/2W, 1%
59	1	R2	Resistor	Std	Std	10	1206	Resistor, Chip, 1/4W, 1%
60	1	R31	Resistor	Std	Std	1k	805	Resistor, Chip, 1/5W, 1%
61	1	R12	Resistor	Std	Std	20	805	Resistor, Chip, 1/5W, 1%
62	1	R1	Resistor	Std	Std	300k	1206	Resistor, Chip, 1/4W, 1%
63	1	R14	Resistor	ERJ8BWFR005V	Panason	5mohm	1206	Resistor, Chip, 1/2W, 1%
64	1	T1	Transformer	750343768	WE		TH type	RM7, 8Pin
65	2	C1-2	Electrolytic capa	KM series	CapXon	15uF, 400V	10X12.5	size, 10mmx12.5mm
66	1	C5	Electrolytic capa	KM series	CapXon	15uF, 400V	10X12.5	size, 10mmx12.5mm
67	1	C14	Electrolytic capa	GF series	CapXon	470uF, 25V	3mmx12mm	size: 8mmx12mm
68	2	C13 C29	Electrolytic soli	PS561M025F080P	CapXon	560uF, 25V	3mmx12mm	size: 8mmx12mm
69	1	Q1	MOSFET	NTMFS6B03NLT1G	ON		S08FL	MOSFET, NChan, 100V
70	1	J1	USB Type C connec	632 723 300 011	WE		TH/SMD	Type C connector, SMT
71	1	U2	PD controller	WT6632FSG14BWT5	Weltrend		S014	PD3.0/QC3.0 protocol controller
72	1	ZD5	Zener	MM3Z10VT1G	ON	10V	SOD323	GENERIC ZENER-DIODE

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BOM (Continued)

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
73	1	ZD2	Zener	MM3Z24VT1G	ON	24V	SOD323	GENERIC ZENER-DIODE
74	4	ESD1-4	ESD	SD05T1G	ON	5V	SOD323	ESD protection device
75	2	L N	1pin connector	std	std		TH type	单根90度排针

References

ON Semiconductor datasheet for NCP1342/4306/, NTMFS6B03, ATP104

ON Semiconductor Design Notes DN05043

CanYon semiconductor datasheet for WT6632F

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